

REPLACEMENT CLAIMS

~~A1~~ 5. (amended) ~~The method of claim 1 wherein said second oxide layer is formed to at least about 60% of a~~ targeted thickness of said second oxide layer.

~~A2~~ 20. (amended) ~~The method of claim 16 wherein said second oxide layer is formed to at least about 60% of a~~ targeted thickness of said second oxide layer.

~~A3~~ 35. (amended) The method of claim 31 wherein said second oxide layer is formed to at least about 60% of a targeted thickness of said second oxide layer.